

NX8311UD

1 310 nm FOR LONG HAUL 2.5 Gb/s InGaAsP MQW-DFB LASER DIODE TOSA

DESCRIPTION

The NX8311UD is a 1 310 nm Multiple Quantum Well (MQW) structured Distributed Feed-Back (DFB) laser diode TOSA (transmitter optical subassembly) with InGaAs monitor PIN-PD in a receptacle type package designed for SFF/SFP transceiver with LC duplex receptacle.

FEATURES

★ • Applications
 STM-16 (L-16.1), SONET OC-48 (LR)

· Internal optical isolator

Optical output power
 Pf = 2.0 mW

• Low threshold current $I_{th} = 10 \text{ mA TYP.} @ T_C = 25^{\circ}C$

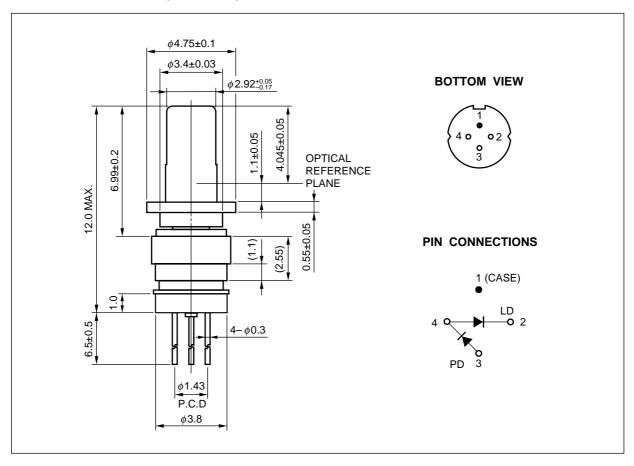
• Wide operating temperature range $Tc = -20 \text{ to } +85^{\circ}\text{C}$

• InGaAs monitor PIN-PD



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★ PACKAGE DIMENSIONS (UNIT: mm)





ORDERING INFORMATION

Part Number	Package	Pin Connections
NX8311UD	ϕ 3.8 mm TOSA	4 0 LD 2 PD 3

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Ratings	Unit
Optical Output Power from Fiber	Pf	5.0	mW
Forward Current of LD	lF	150	mA
Reverse Voltage of LD	VR	2.0	V
Forward Current of PD	lF	2.0	mA
Reverse Voltage of PD	VR	15	V
Operating Case Temperature	Tc	-20 to +85	°C
Storage Temperature	T _{stg}	-40 to +85	°C
Lead Soldering Temperature	T _{sld}	350 (3 sec.)	°C

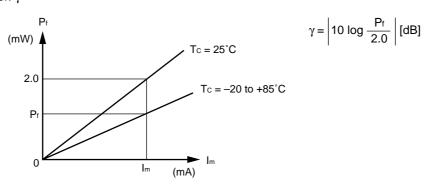
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ELECTRO-OPTICAL CHARACTERISTICS (Tc = -20 to +85°C, unless otherwise specified)

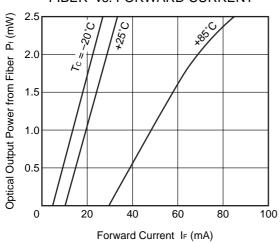
Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Operating Voltage	Vop	CW, P _f = 2.0 mW		1.2	1.6	V
Threshold Current	Ith	CW,	2		50	mA
		CW, Tc = 25°C	4	10	20	
Optical Output Power from Fiber	Pf	CW		2.0		mW
Modulation Current	Imod	CW, P _f = 2.0 mW	7		50	mA
		CW, P _f = 2.0 mW, Tc = 25°C	9	20	30	
Differential Efficiency	$\eta_{ ext{d}}$	CW, P _f = 2.0 mW	0.04		0.29	W/A
		CW, P _f = 2.0 mW, Tc = 25°C	0.07	0.10	0.20	
Peak Emission Wavelength	λρ	CW, P _f = 2.0 mW, RMS (-20 dB)	1 280		1 335	nm
Side Mode Suppression Ratio	SMSR	CW, P _f = 2.0 mW	30			dB
Rise Time	tr	Ib = Ith, 10-90%			200	ps
Fall Time	t f	Ib = Ith, 90-10%			200	ps
Monitor Current	Im	CW, V _R = 1.5 V, P _f = 1.0 mW	100		2 000	μΑ
Monitor Dark Current	ΙD	V _R = 1.5 V			500	nA
		V _R = 1.5 V, T _C = 25°C			50	
Tracking Error ^{*1}	γ	CW, I _m = const. (@ P _f = 2.0 mW)	-1.0		1.0	dB
Connector Repeatability	_	With master pigtail	-1.0		1.0	dB
Optical Isolation	Is	CW, P _f = 2.0 mW	20			dB

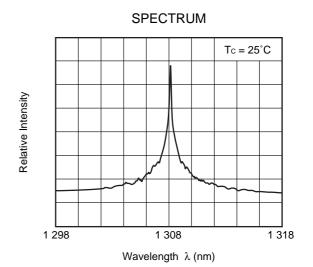
*1 Tracking Error: γ



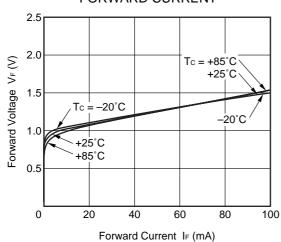
★ TYPICAL CHARACTERISTICS (Tc = 25°C, unless otherwise specified)







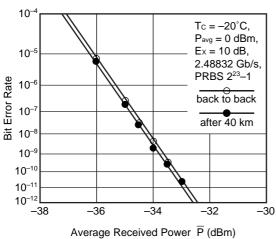
FORWARD VOLTAGE vs. FORWARD CURRENT



Remark The graphs indicate nominal characteristics.

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ERROR RATE CHARACTERISTICS



EYE DIAGRAM

STM16/0C48 total wfms 500 failed smpls 0 region

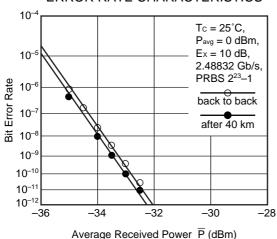
Relative Intensity (20 mV/div.)

Relative Intensity (20 mV/div.)

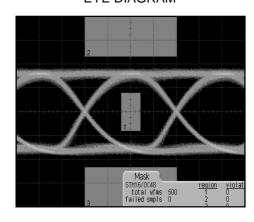
Relative Intensity (20 mV/div.)

Back to Back (100 ps/div.)

ERROR RATE CHARACTERISTICS

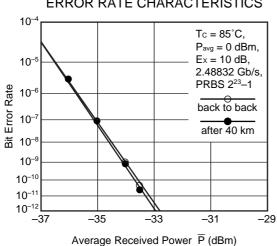


EYE DIAGRAM

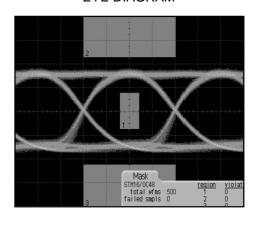


Back to Back (100 ps/div.)

ERROR RATE CHARACTERISTICS



EYE DIAGRAM



Back to Back (100 ps/div.)

Remark The graphs indicate nominal characteristics.



LD ϕ 3.8 mm FP-TOSA PACKAGES FAMILY FOR OPTICAL FIBER COMMUNICATIONS

			Electi	ro-Optical	Characte	ristics		
	Absolute Max	imum Ratings	@Tc = 25°C	@Tc				
Part Number	Tc (°C)	T _{stg} (°C)	I _{th} (mA)	P _f (mW)	λc (nm)		Application	Package
			TYP.	TYP.	MIN.	MAX.		
NX7312UA	-40 to +85	-40 to +85	8	0.2	1 274	1 356	156 Mb/s: STM-1 (S-1.1)	ϕ 3.8 mm TOSA
							622 Mb/s: STM-4 (S-4.1)	
NX7313UA	-40 to +85	-40 to +85	8	0.6	1 270	1 355	1.25 Gb/s: GbE	ϕ 3.8 mm TOSA
NX7314UA	-40 to +85	-40 to +85	8	1.0	1 263	1 360	156 Mb/s: STM-1 (L-1.1)	ϕ 3.8 mm TOSA
NX7315UA	-40 to +85	-40 to +85	8	0.6	1 266	1 360	2.5 Gb/s: STM-16 (I-16)	ϕ 3.8 mm TOSA

LD ϕ 3.8 mm DFB-TOSA PACKAGES FAMILY FOR OPTICAL FIBER COMMUNICATIONS

			Electr	o-Optical	Characte	ristics				
Deat Morellon	Absolute Max	imum Ratings	@Tc = 25°C		@Tc		Annillandina	Davisana		
Part Number	Tc (°C)	T _{stg} (°C)	I _{th} (mA)	P _f (mW)	λ _P (nm)		·		Application	Package
			TYP.	TYP.	MIN.	MAX.				
NX8310UA	-40 to +85	-40 to +85	10	2.0	1 280	1 335	622 Mb/s: STM-4 (L-4.1)	φ 3.8 mm TOSA		
NX8311UD	-20 to +85	-40 to +85	10	2.0	1 280	1 335	2.5 Gb/s: STM-16 (L-16.1)	ϕ 3.8 mm TOSA		
NX8312UA	-20 to +85	-40 to +85	10	1.0	1 280	1 335	2.5 Gb/s: STM-16 (S-16.1)	φ 3.8 mm TOSA		
NX8312UD	-20 to +85	-40 to +85	10	1.0	1 280	1 335	2.5 Gb/s: STM-16 (S-16.1)	φ 3.8 mm TOSA		

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REFERENCE

Document Name	Document No.
OPTICAL SEMICONDUCTOR DEVICES FOR FIBEROPTIC COMMUNICATIONS SELECTION GUIDE	PX10161E
Opto-Electronics Devices Pamphlet	PX10160E

IEC NX8311UD

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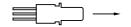
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NEC NX8311UD

SAFETY INFORMATION ON THIS PRODUCT



SEMICONDUCTOR LASER



AVOID EXPOSURE-Invisible Laser Radiation is emitted from this aperture

A laser beam is emitted from this diode during operation.
The laser beam, visible or invisible, directly or indirectly, may cause injury to the eye or loss of
eyesight.
Do not look directly into the laser beam.
Avoid exposure to the laser beam, any reflected or collimated beam.
This product uses gallium arsenide (GaAs).
GaAs vapor and powder are hazardous to human health if inhaled or ingested, so please observe the following points.
• Follow related laws and ordinances when disposing of the product. If there are no applicable laws and/or ordinances, dispose of the product as recommended below.
 Commission a disposal company able to (with a license to) collect, transport and dispose of materials that contain arsenic and other such industrial waste materials.
Exclude the product from general industrial waste and household garbage, and ensure that the product is controlled (as industrial waste subject to special control) up until final disposal.
• Do not burn, destroy, cut, crush, or chemically dissolve the product.
• Do not lick the product or in any way allow it to enter the mouth.
A glass-fiber is attached on the product. Handle with care.
 When the fiber is broken or damaged, handle carefully to avoid injury from the damaged part or fragments.

▶For further information, please contact

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